



TU1B-1

Broadband Class-E Power Amplifier Designed by Lumped-Element Network Transforms and GaN FETs

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SKYWORKS®

Newbury Park, CA

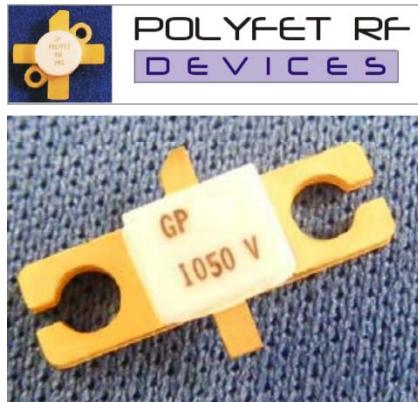


Outline

- Broadband Class-E Amplifier
- Network Transforms
- Transformation Sequence
- Output Network Topology Characteristics
- Prototype Performance
- Conclusions

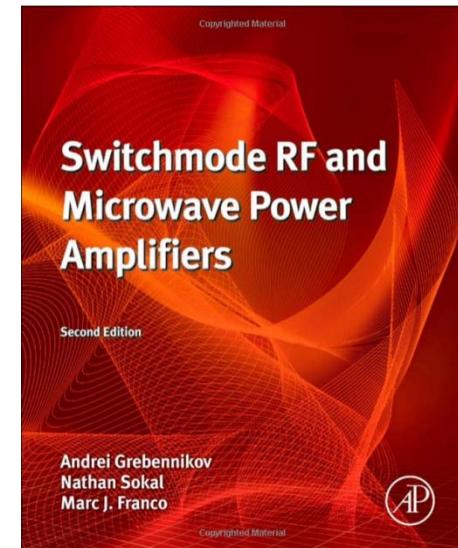
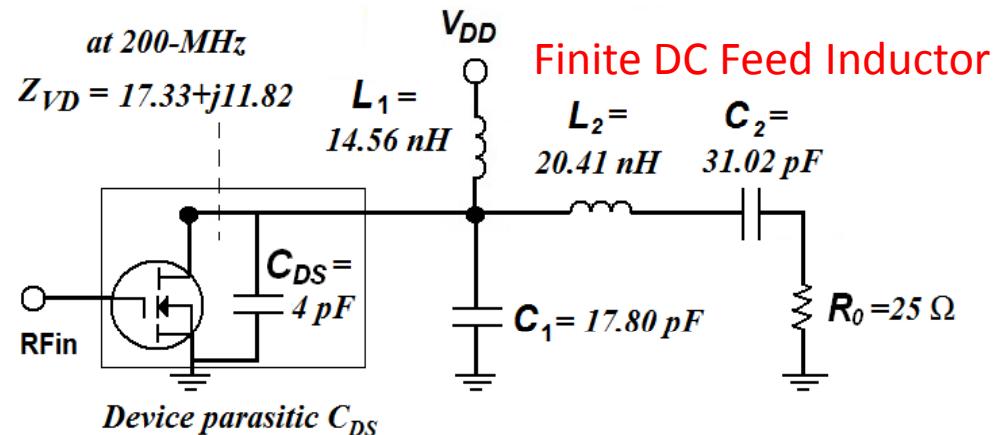


Broadband Class-E Amplifier



Polyfet GP2001
 $C_{oss}=4\text{pF}$

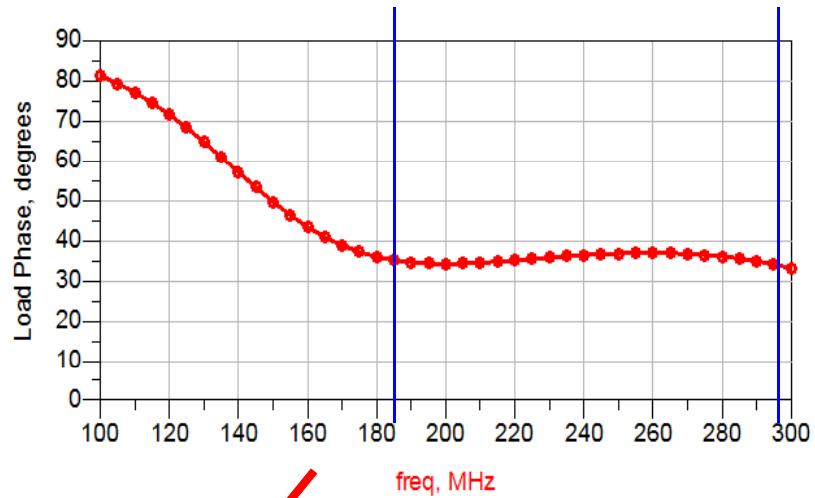
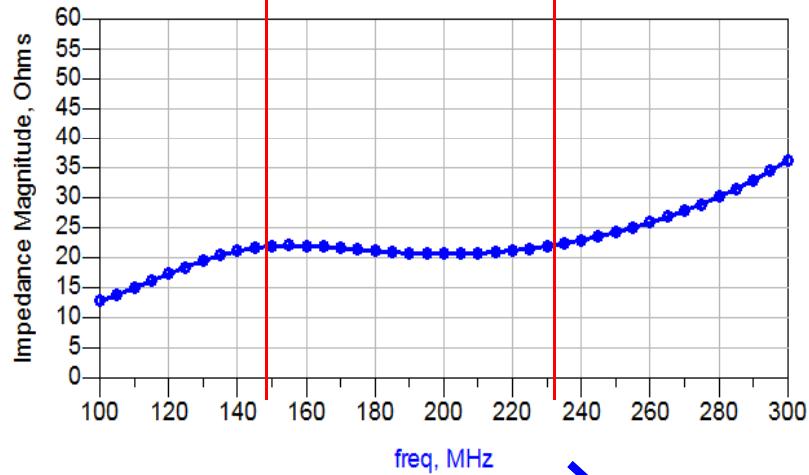
Design Frequency: 200-MHz
Output Power: 18-W (42.5 dBm)
Supply Voltage: 18.2 V
Load Resistance: 25- Ω



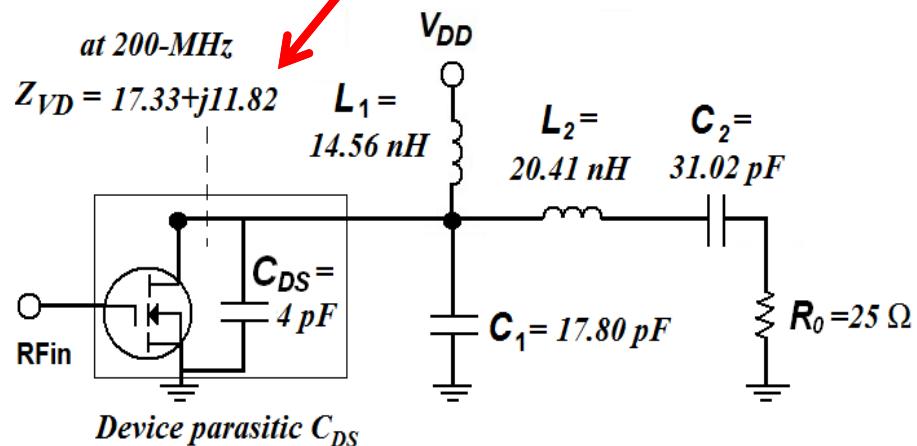
Switchmode RF and Microwave
Power Amplifiers,
by Grebennikov, Sokal and Franco



Broadband Class-E Amplifier

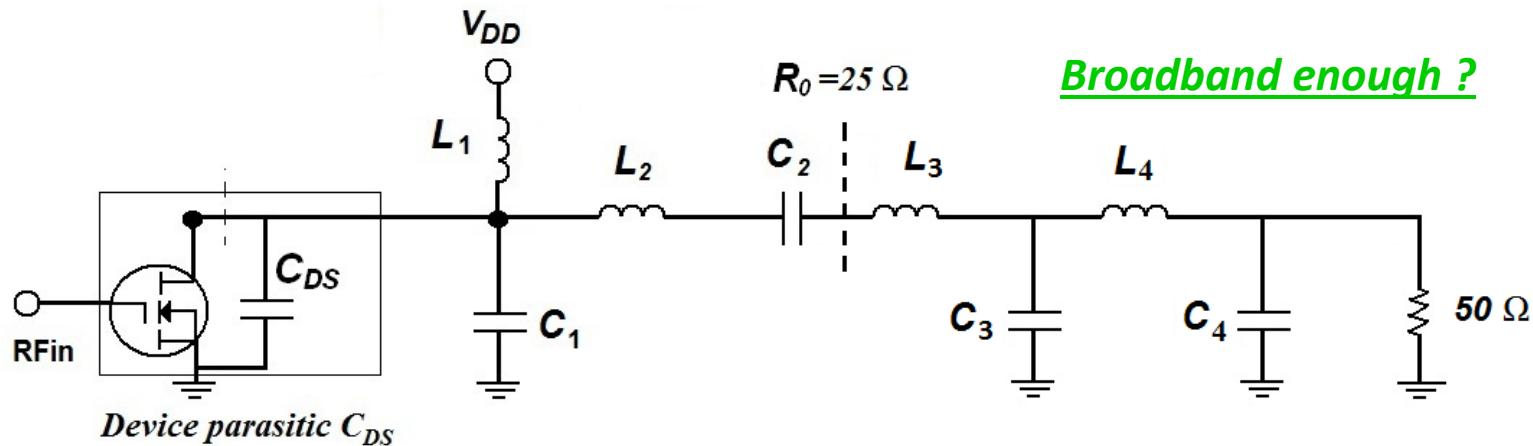


- Maintains load impedance and phase over a wide frequency range
- Requires broadband matching to 50-Ohms





Broadband Class-E Amplifier Topology for Broadband Performance



Matched to 50-Ohms

Non-optimum reactances at the harmonics

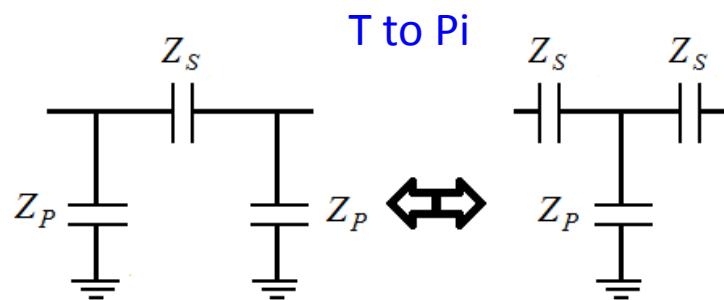
Minimum of 7 components

3 Inductors
4 capacitors



Network Transforms

- Broadband impedance matching
- Equivalent at all frequencies
- Standard component values
- PWB parasitics management; i.e: stray capacitance to ground
- A shunt component to ground at all nodes
- Topology selection for a given application
- Minimum number of components
- Reduced insertion loss and more economic

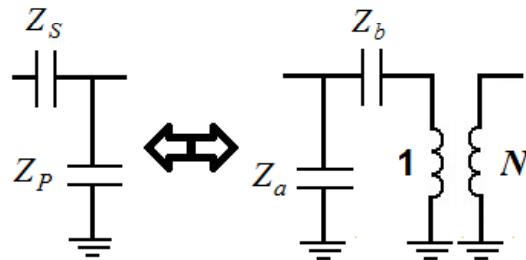




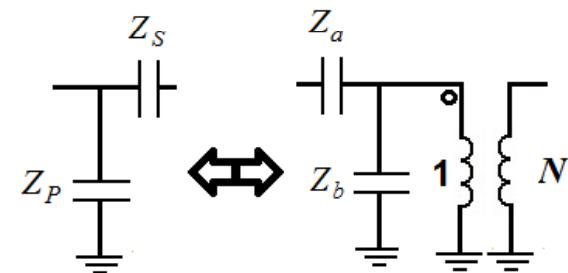
Network Transforms

Example of Network Transforms

L-right to L-left



L-left to L-right



Equivalent Networks
At All Frequencies

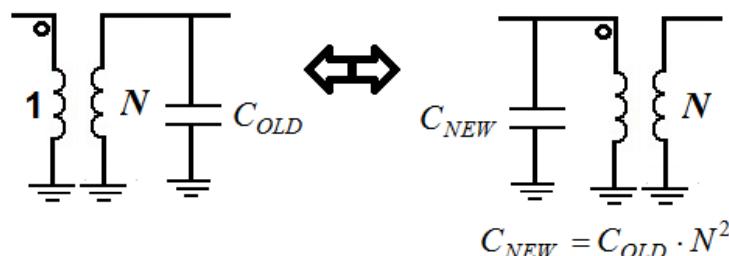
$$N = 1 + \frac{Z_s}{Z_p}$$

$$Z_a = \frac{Z_s}{N} \quad Z_b = \frac{Z_p}{N}$$

$$N = \frac{Z_p}{Z_s + Z_p}$$

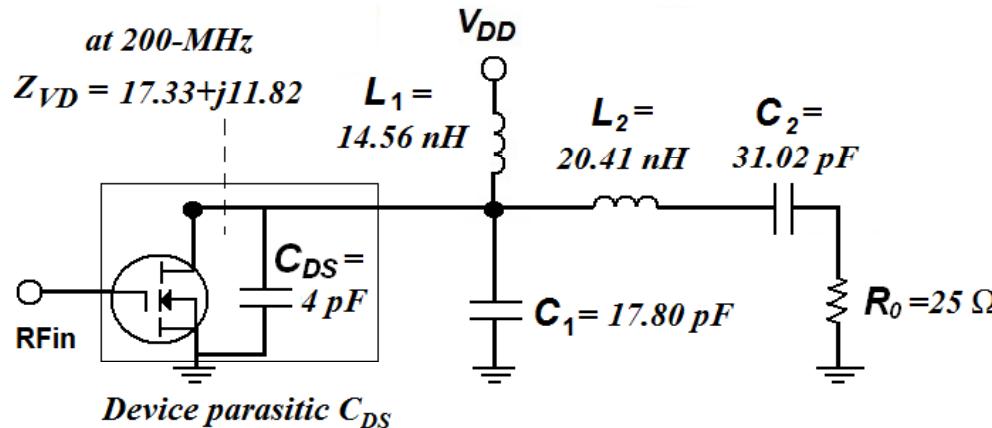
$$Z_a = \frac{Z_p}{N} \quad Z_b = \frac{Z_s}{N}$$

Move transformer right



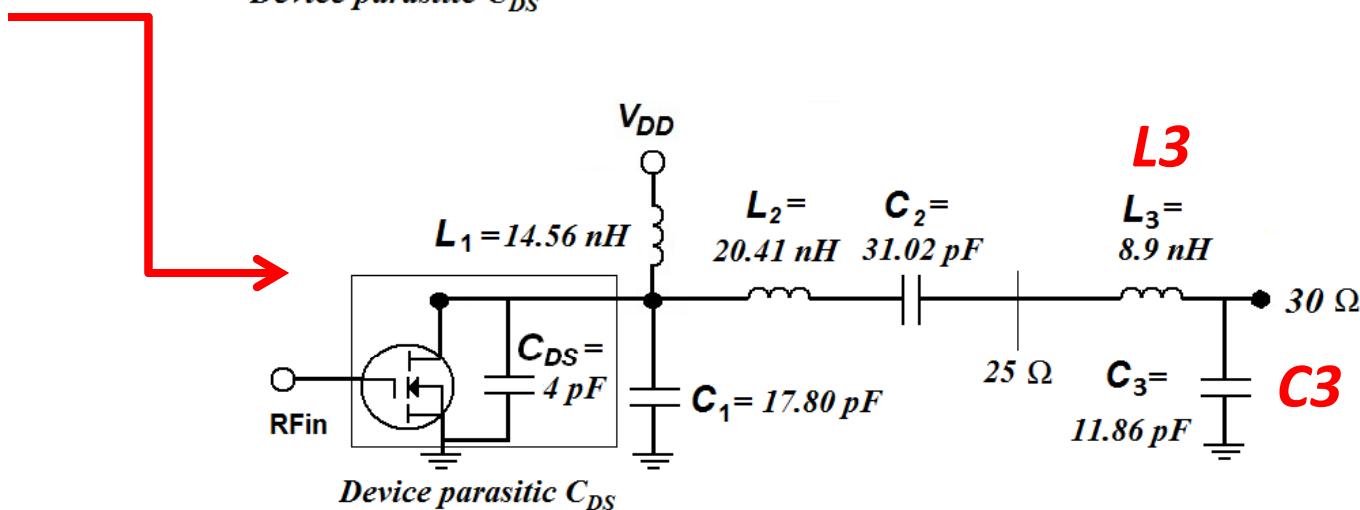


Network Transforms Sequence



Original designed network

25-Ω load impedance



L3

C3

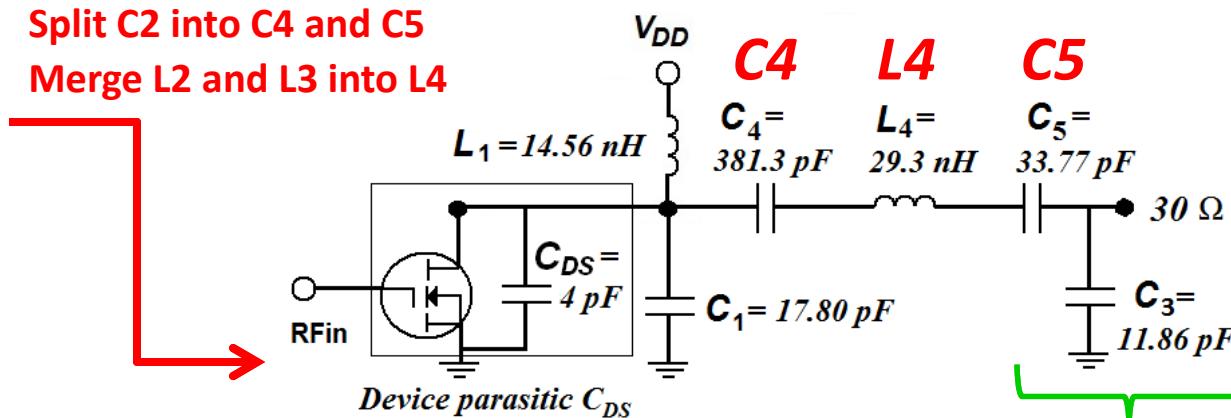
Matching from 25 to 30 Ohms



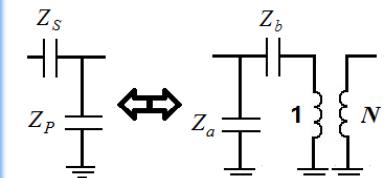
Network Transforms Sequence

Split C2 into C4 and C5

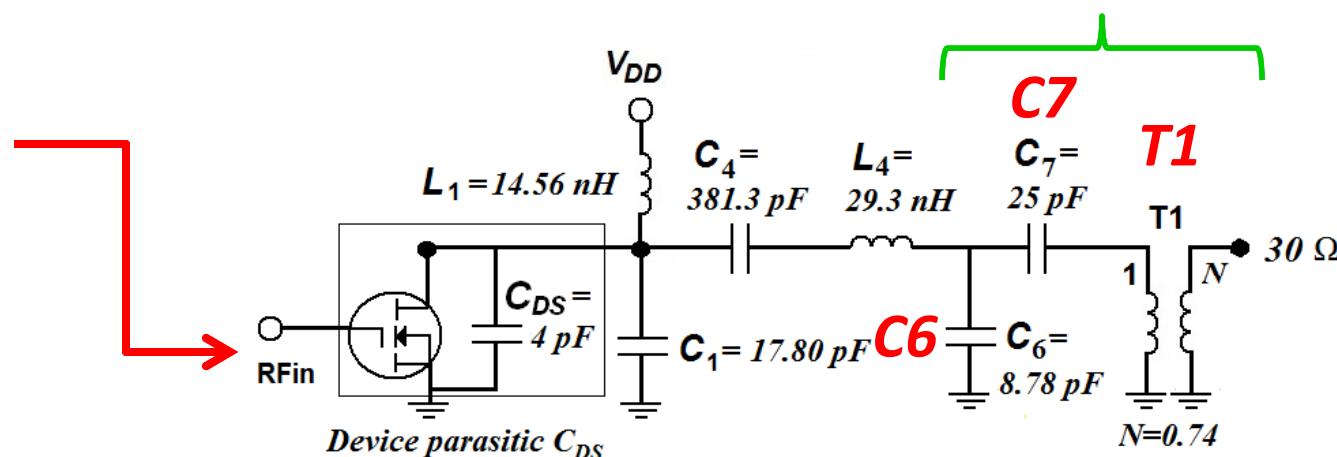
Merge L2 and L3 into L4



L-left to L-right



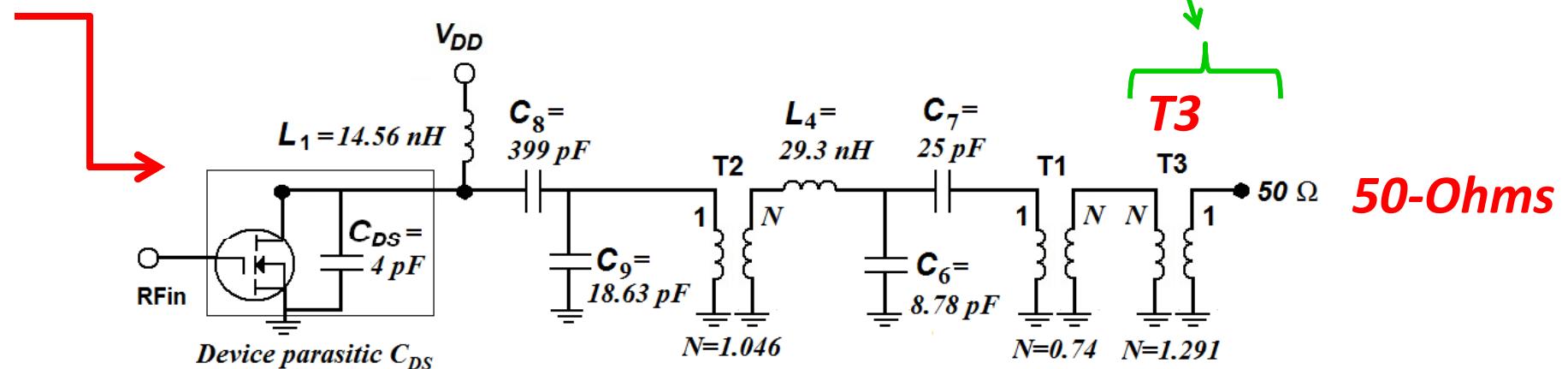
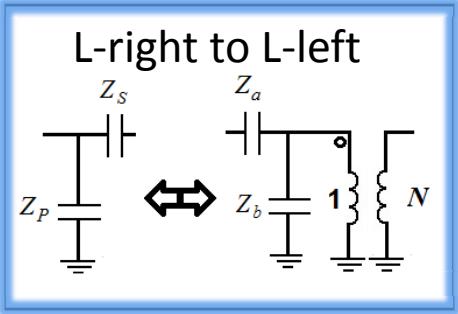
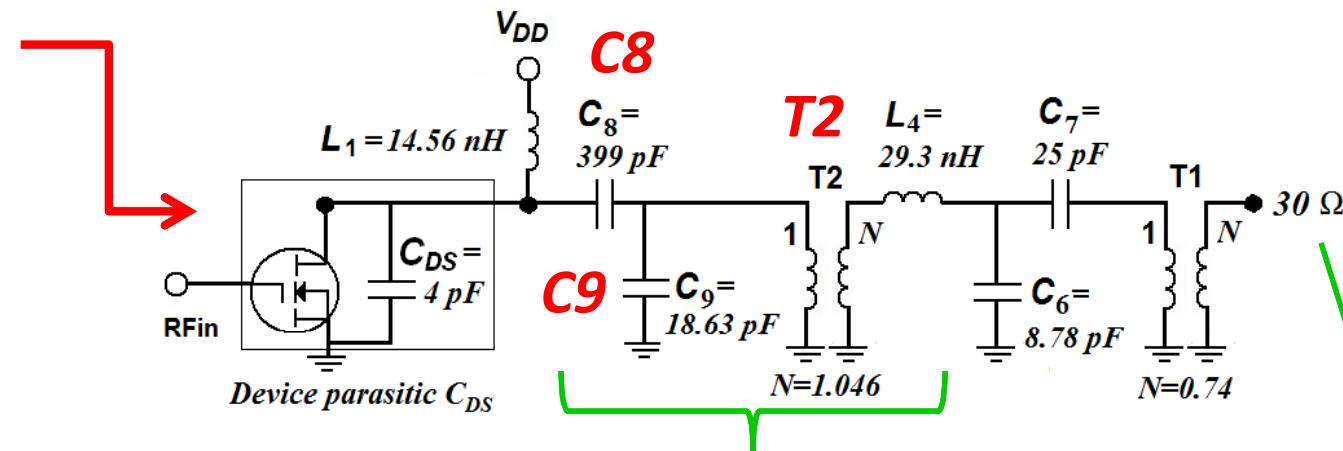
Apply L-left to L-right to C5 and C3





Network Transforms Sequence

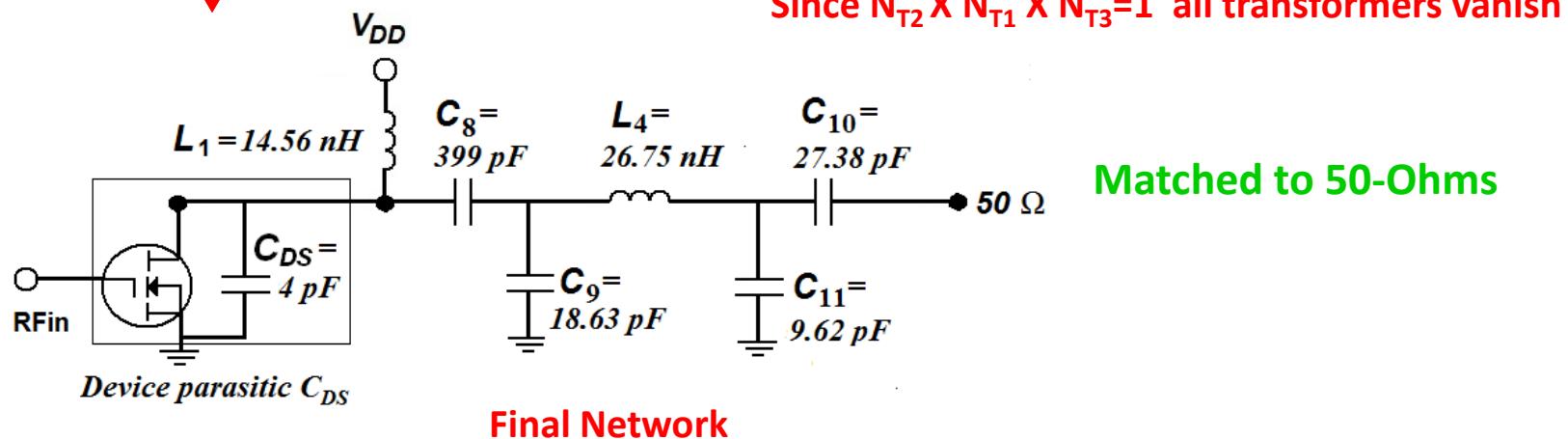
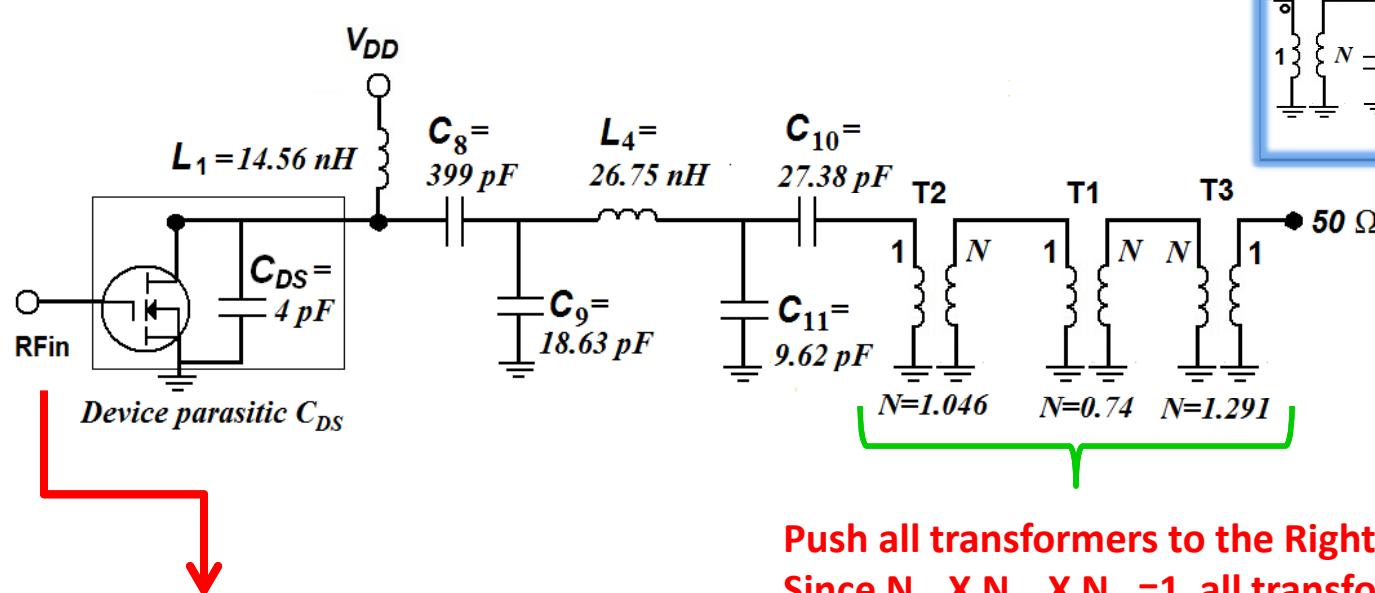
Apply L-right to L-left to C4 and C1



Add transformer T3 to match to 50 Ohms



Network Transforms Sequence





Frequency response

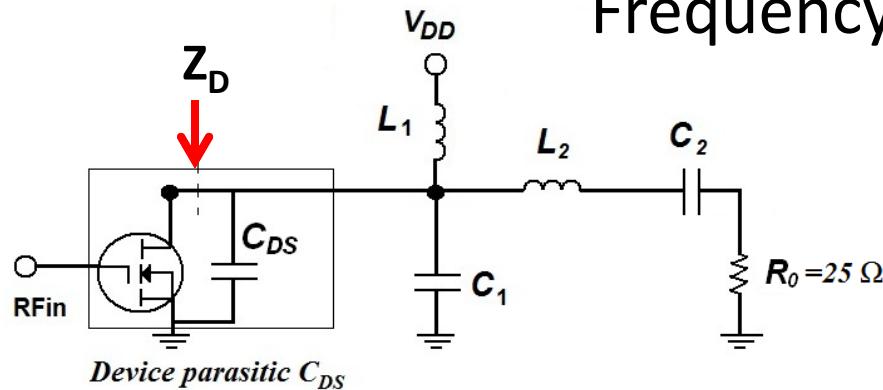


Fig. 3

Device parasitic C_{DS}

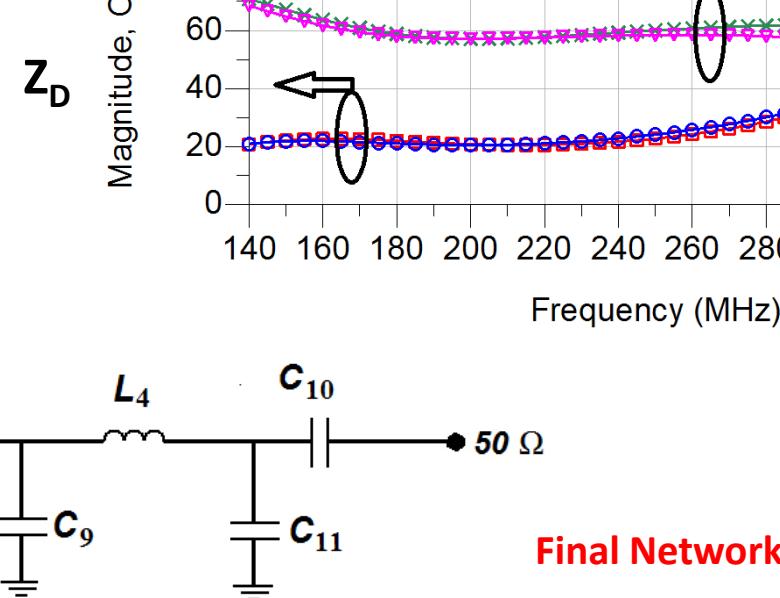


Fig. 5c

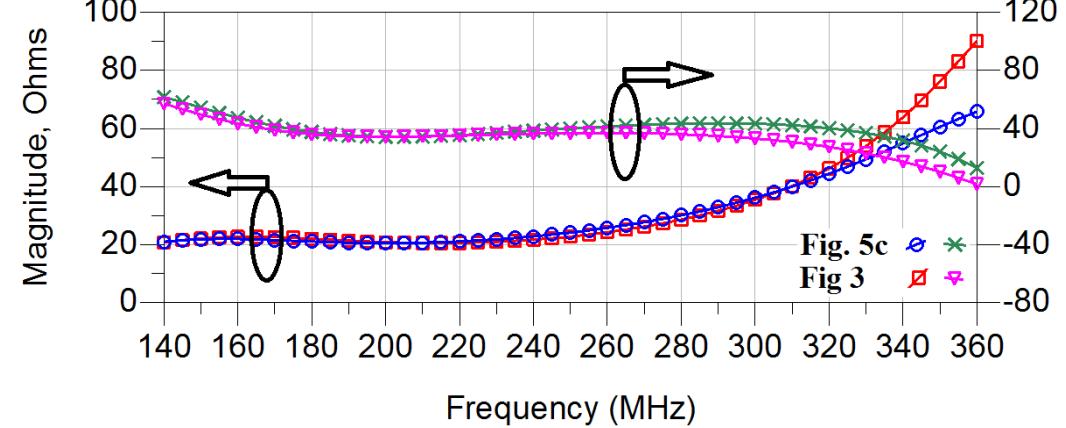
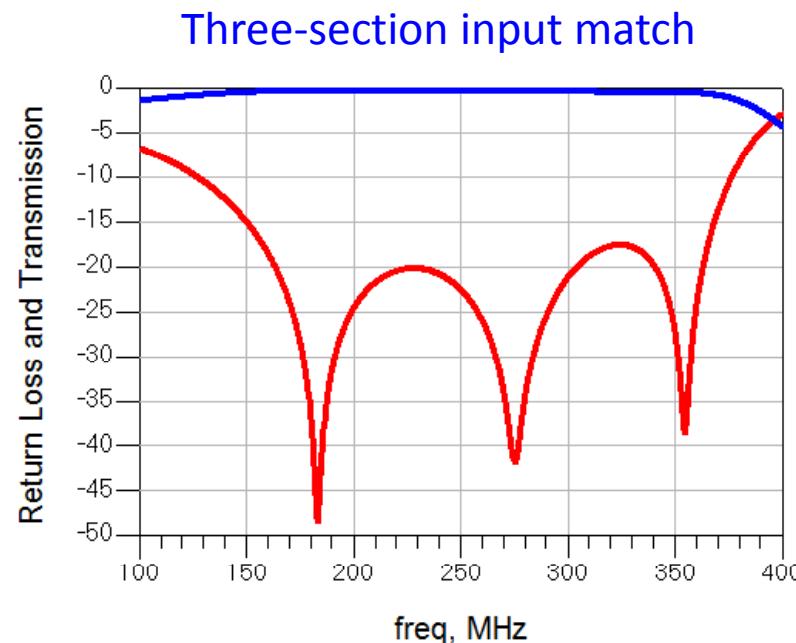
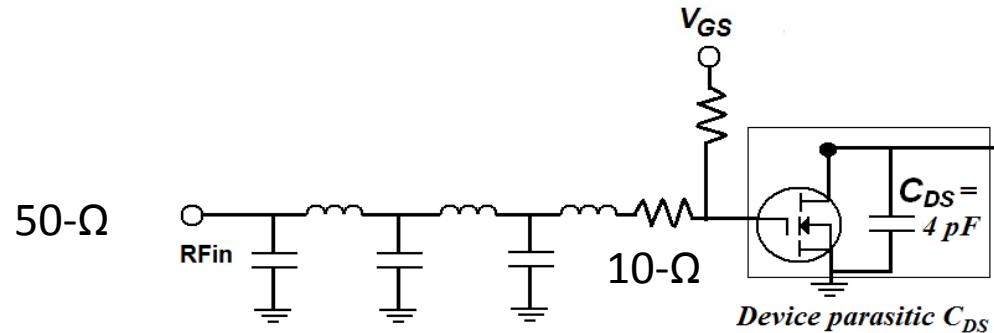


Fig. 5c
Fig 3

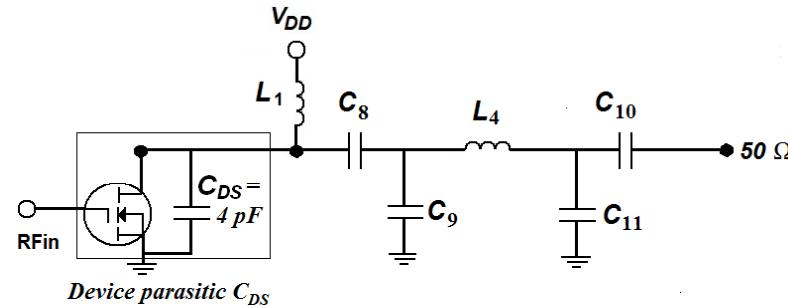


Input Matching



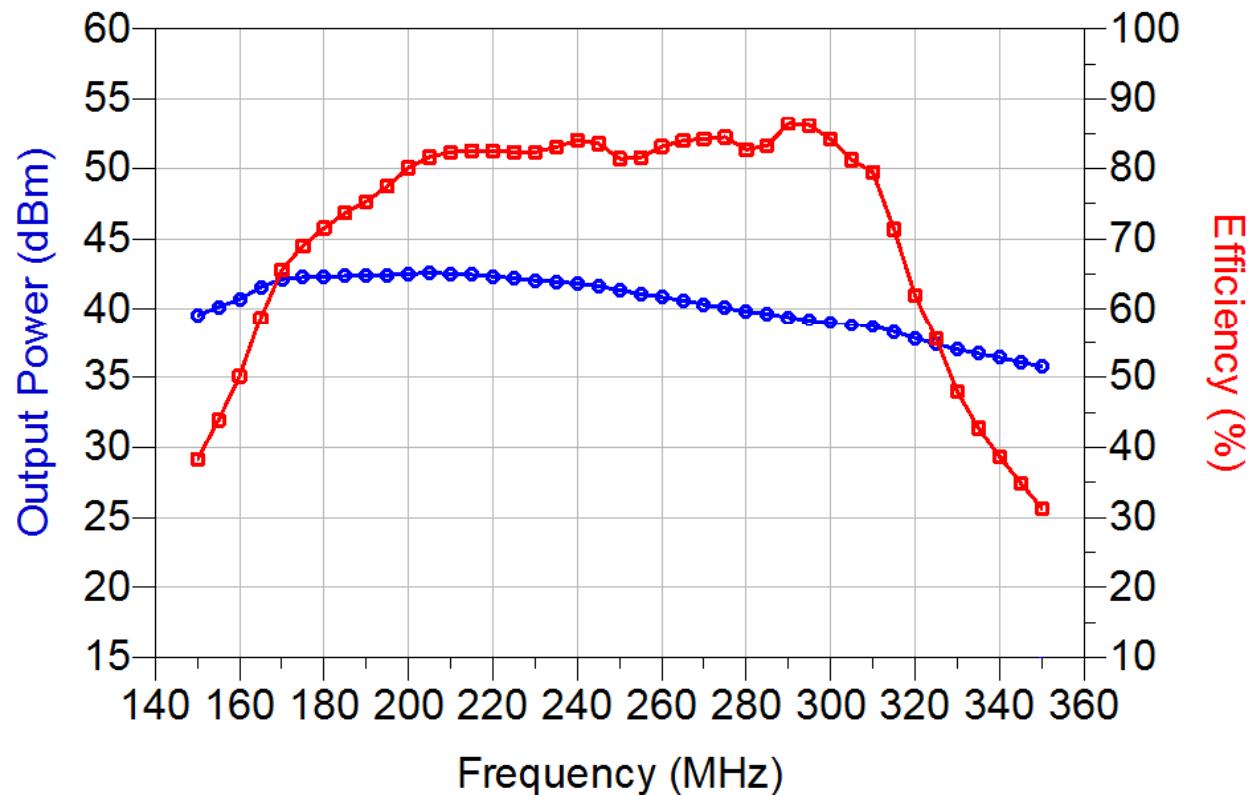


Prototype





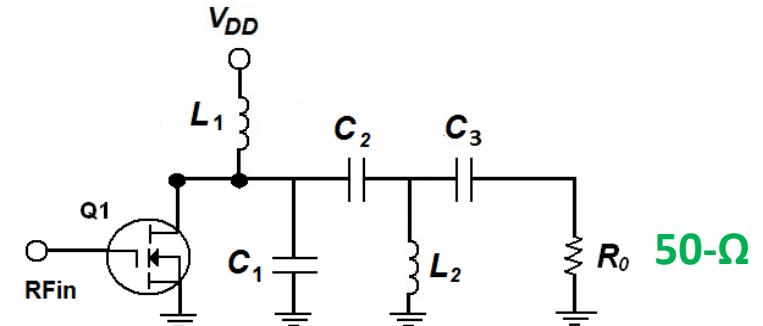
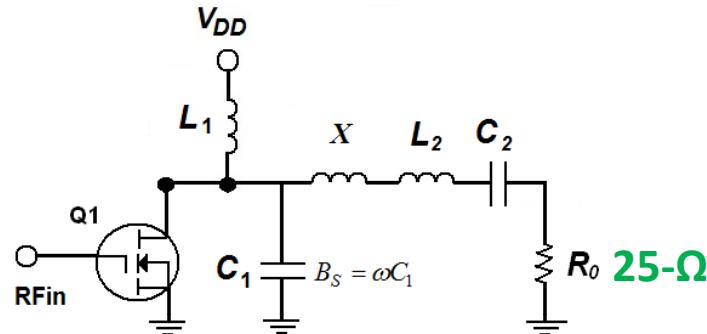
Broadband Performance



Fixed Input power of 28-dBm over the frequency range

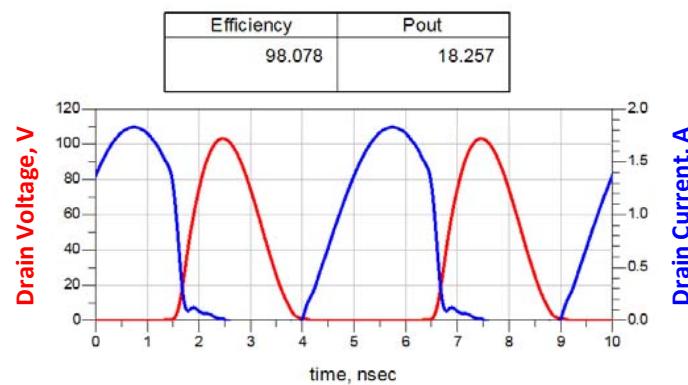


Other Network Transforms and True-transient Class-E Network Topologies

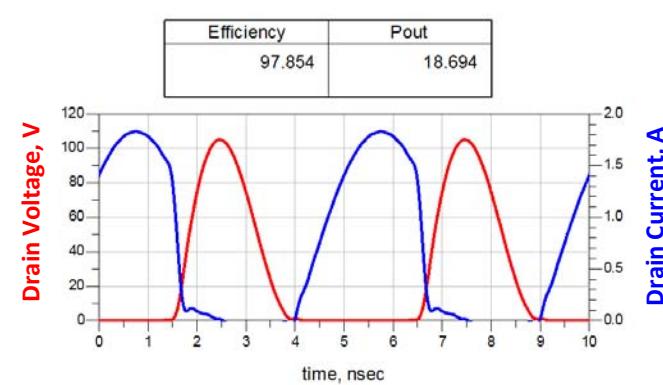


Equivalent networks at all frequencies

True broadband
impedance matching



Exact equivalent
waveforms





Conclusions

- Understanding where to apply a given network transform determines the final topology
- The number of topologies are infinite; Choose the most suitable for your application
- Attention has to be paid for realizable component values
- Impedance matching can be perform with ideal transformers and then eliminate the transformer using a network transform
- In this example, a class-E amplifier achieves excellent broadband performance by using exact equivalent transforms for broadband matching and topology transformation.



Thanks to



RF POWER GAN TRANSISTOR

20.0 Watts Single Ended

Package Style GP

HIGH EFFICIENCY, LINEAR

HIGH GAIN, LOW NOISE

ROHS COMPLIANT

Suitable for use across 1-3000Mhz



- Thanks to Mr. Jerome Citrolo and Marcos Cervantes
Provided the GaN FET GP2001 used for the prototypes